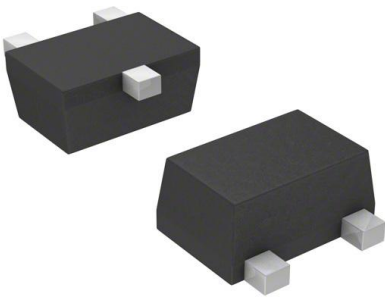


# BCR 192F E6327 Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	BCR 192F E6327-DG
Manufacturer	<a href="#">Infineon Technologies</a>
Manufacturer Product Number	BCR 192F E6327
Description	TRANS PREBIAS PNP 50V TSFP-3
Detailed Description	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased 50 V 100 mA 200 MHz 250 mW Surface Mount PG-TSFP-3



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

BCR 192F E6327

Series:

-

Transistor Type:

PNP - Pre-Biased

Voltage - Collector Emitter Breakdown (Max):

50 V

Resistor - Emitter Base (R2):

47 kOhms

Vce Saturation (Max) @ Ib, Ic:

300mV @ 500µA, 10mA

Frequency - Transition:

200 MHz

Mounting Type:

Surface Mount

Supplier Device Package:

PG-TSFP-3

Manufacturer:

Infineon Technologies

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Resistor - Base (R1):

22 kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

70 @ 5mA, 5V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

250 mW

Package / Case:

SOT-723

Base Product Number:

BCR 192

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

REACH Status:

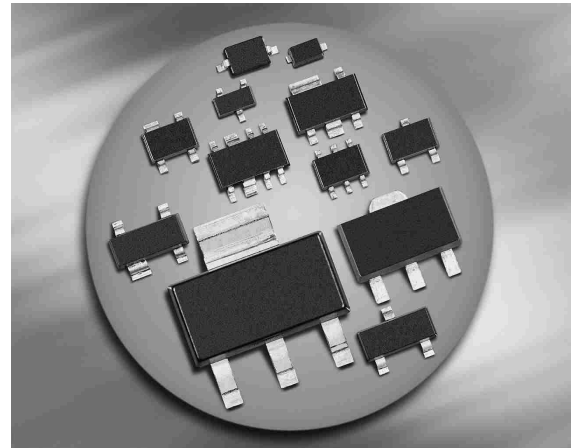
REACH Unaffected

HTSUS:

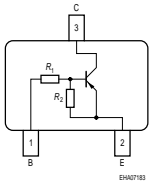
8541.21.0075

### PNP Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ( $R_1 = 22k\Omega$ ,  $R_2 = 47k\Omega$ )
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101



### BCR192/W



Type	Marking	Pin Configuration						Package
		1=B	2=E	3=C	-	-	-	
BCR192	WPs	1=B	2=E	3=C	-	-	-	SOT23
BCR192W	WPs	1=B	2=E	3=C	-	-	-	SOT323

### Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$	50	V
Collector-base voltage	$V_{CBO}$	50	
Input forward voltage	$V_{i(fwd)}$	60	
Input reverse voltage	$V_{i(rev)}$	10	
Collector current	$I_C$	100	mA
Total power dissipation-	$P_{tot}$	200	mW
BCR192, $T_S \leq 102^\circ\text{C}$			
BCR192W, $T_S \leq 124^\circ\text{C}$		250	
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	150 ... -65	



### Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{thJS}$		K/W
BCR192		≤ 240	
BCR192W		≤ 105	

### Electrical Characteristics at $T_A = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

### DC Characteristics

Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	$I_{CBO}$	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$	$I_{EBO}$	-	-	227	$\mu\text{A}$
DC current gain <sup>2)</sup> $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	$h_{FE}$	70	-	-	-
Collector-emitter saturation voltage <sup>2)</sup> $I_C = 10 \text{ mA}, I_B = 0,5 \text{ mA}$	$V_{CEsat}$	-	-	0.3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(off)}$	0.5	-	1.2	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0,3 \text{ V}$	$V_{i(on)}$	0.8	-	2.5	
Input resistor	$R_1$	15	22	29	$\text{k}\Omega$
Resistor ratio	$R_1/R_2$	0.42	0.47	0.52	-

### AC Characteristics

Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	$f_T$	-	200	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_{cb}$	-	3	-	pF

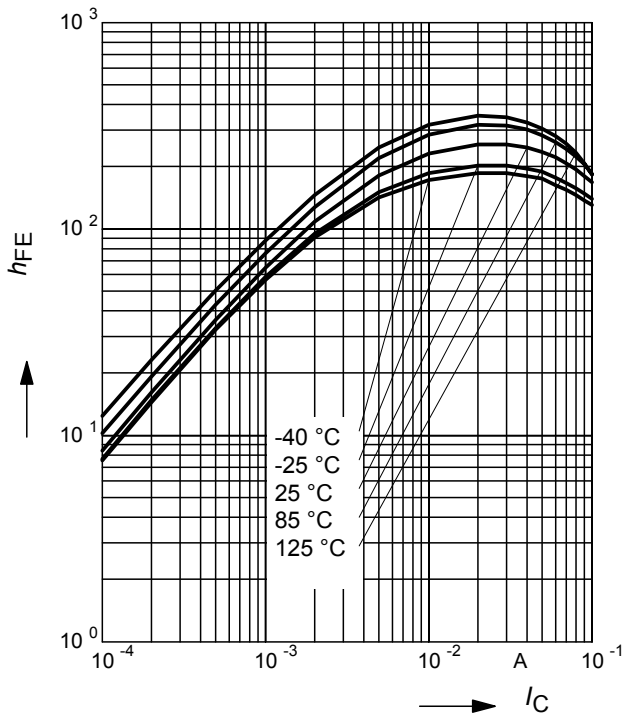
<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note AN077 (Thermal Resistance Calculation)

<sup>2)</sup>Pulse test:  $t < 300\mu\text{s}; D < 2\%$



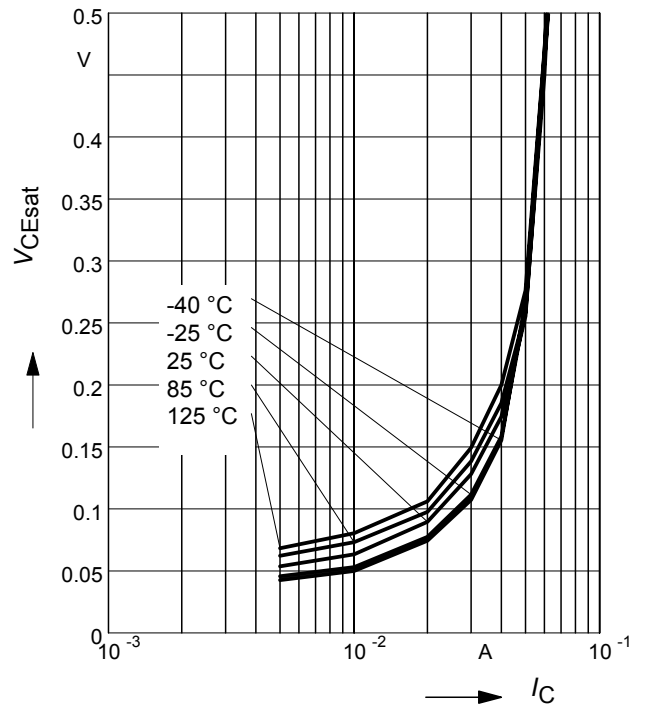
**DC current gain  $h_{FE} = f(I_C)$**

$V_{CE} = 5\text{ V}$  (common emitter configuration)



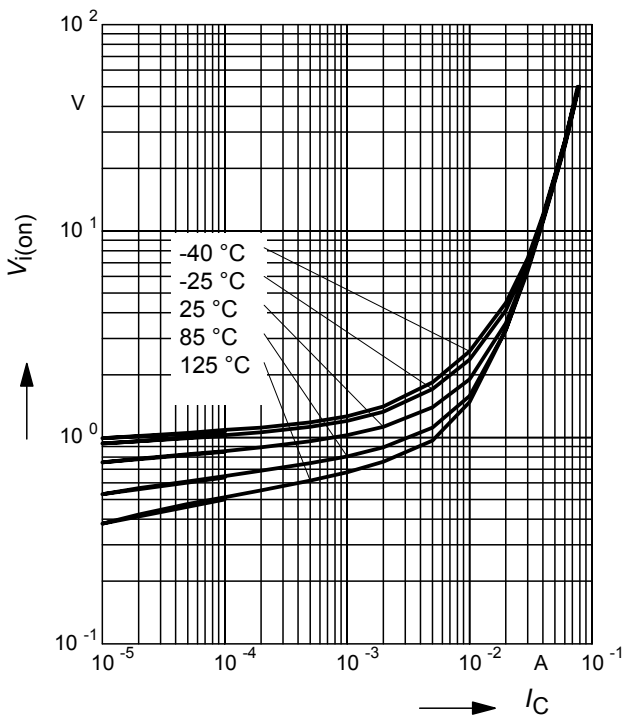
**Collector-emitter saturation voltage**

$V_{CEsat} = f(I_C), I_C/I_B = 20$



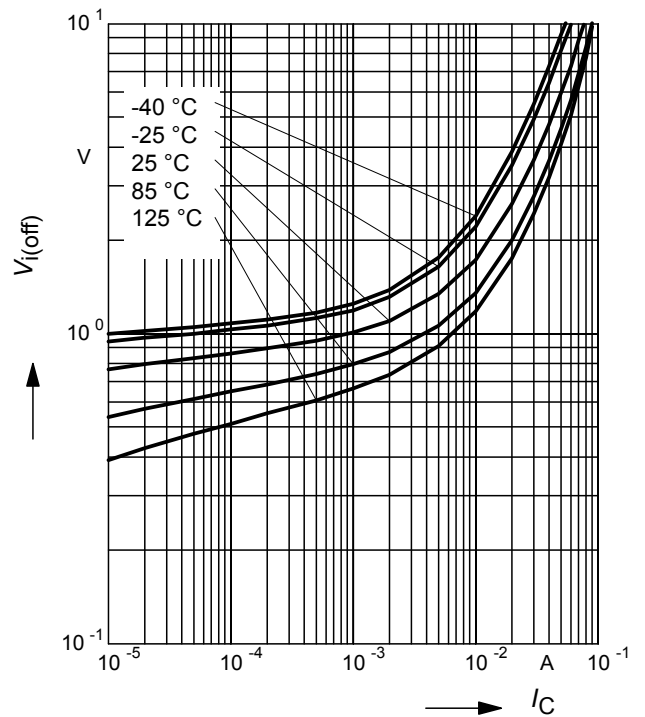
**Input on Voltage  $V_{i(on)} = f(I_C)$**

$V_{CE} = 0.3\text{ V}$  (common emitter configuration)



**Input off voltage  $V_{i(off)} = f(I_C)$**

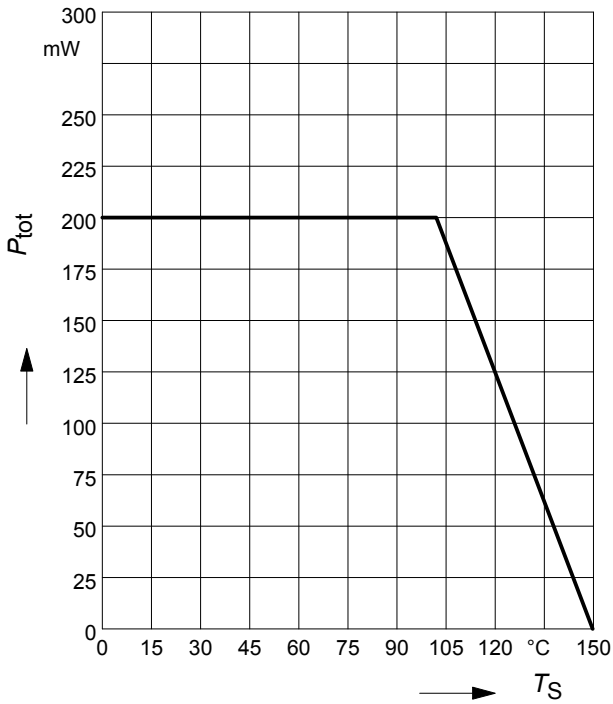
$V_{CE} = 5\text{ V}$  (common emitter configuration)





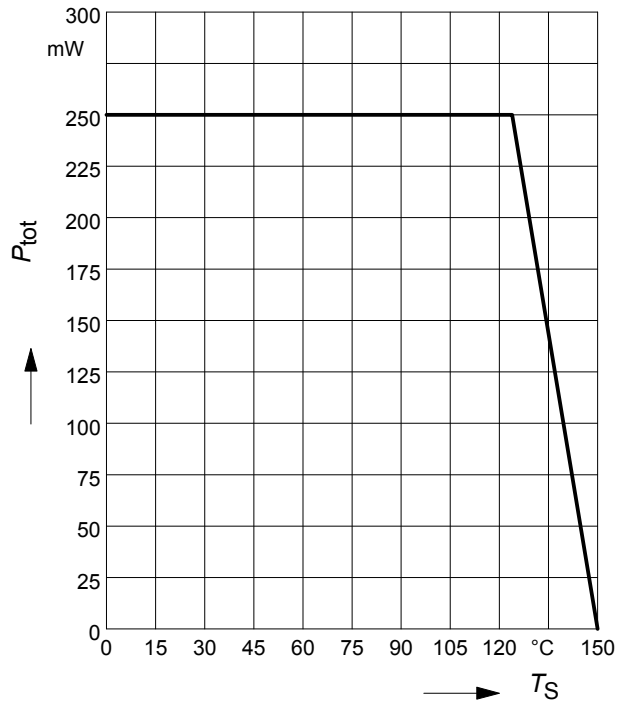
**Total power dissipation  $P_{tot} = f(T_S)$**

BCR192



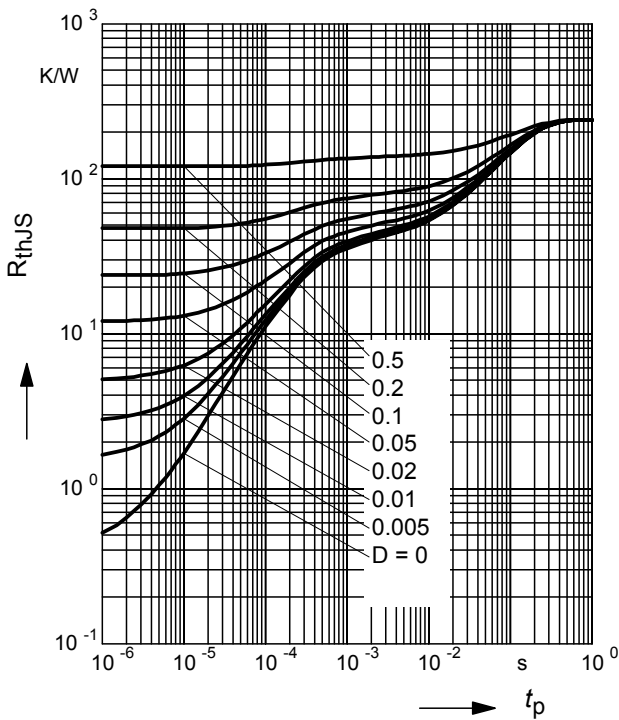
**Total power dissipation  $P_{tot} = f(T_S)$**

BCR192W



**Permissible Pulse Load  $R_{thJS} = f(t_p)$**

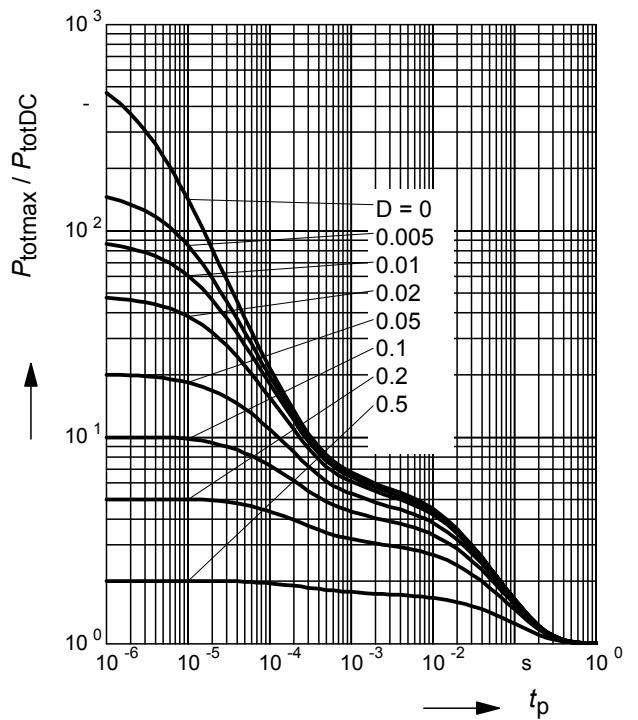
BCR192



**Permissible Pulse Load**

$P_{totmax}/P_{totDC} = f(t_p)$

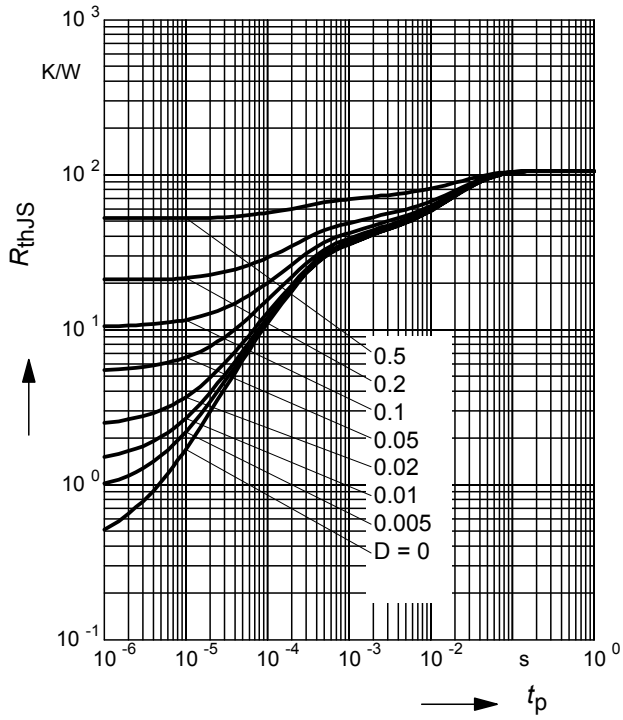
BCR192





**Permissible Puls Load  $R_{thJS} = f(t_p)$**

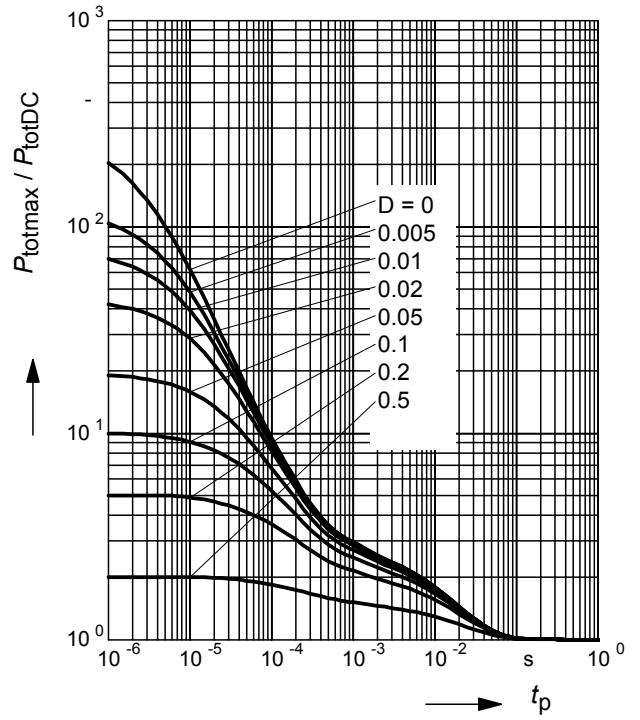
BCR192W



**Permissible Pulse Load**

$P_{totmax}/P_{totDC} = f(t_p)$

BCR192W

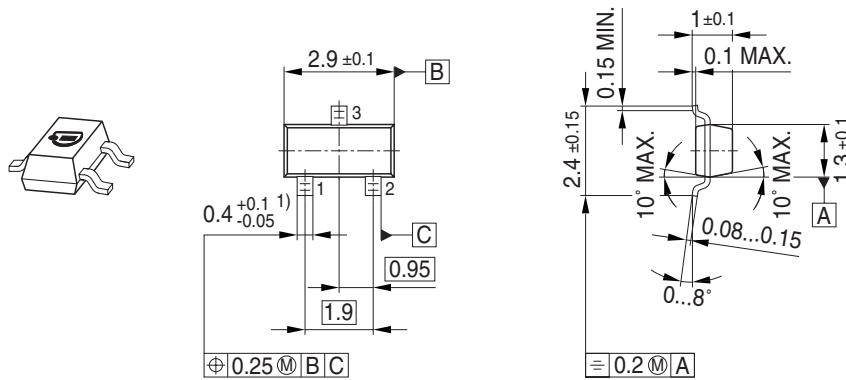




Package SOT23

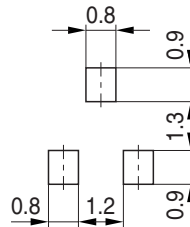
BCR192...

Package Outline

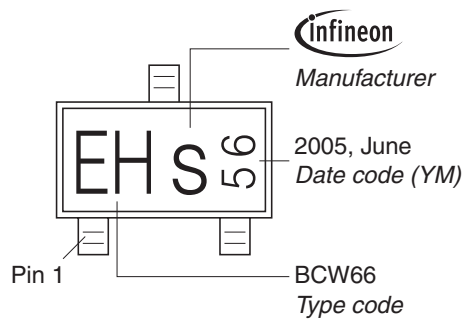


1) Lead width can be 0.6 max. in dambar area

Foot Print

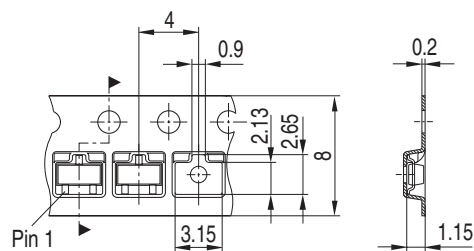


Marking Layout (Example)



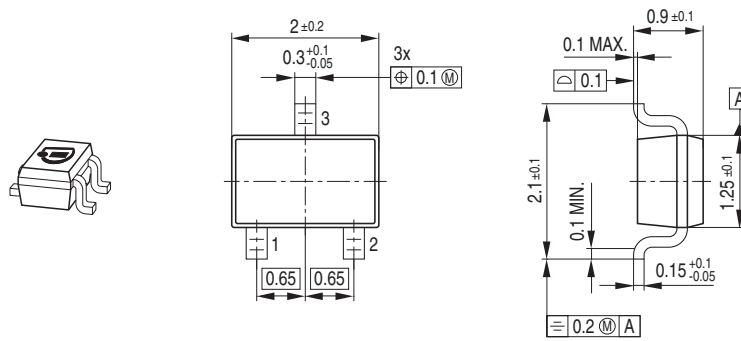
Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel  
 Reel ø330 mm = 10.000 Pieces/Reel

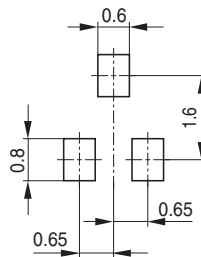




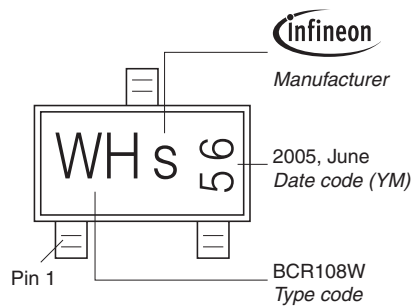
## Package Outline



## Foot Print

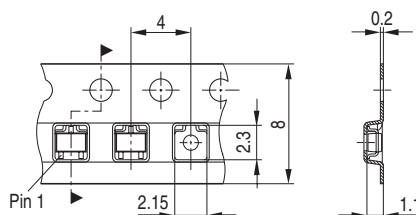


## Marking Layout (Example)



## Standard Packing

Reel  $\varnothing 180$  mm = 3.000 Pieces/Reel  
 Reel  $\varnothing 330$  mm = 10.000 Pieces/Reel





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